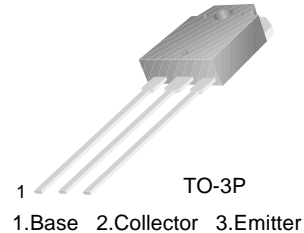


# FJA13009

## High Voltage Switch Mode Applications

- High Speed Switching
- Suitable for Switching Regulator and Motor Control



## NPN Silicon Transistor

### Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	700	V
$V_{CEO}$	Collector-Emitter Voltage	400	V
$V_{EBO}$	Emitter-Base Voltage	9	V
$I_C$	Collector Current (DC)	12	A
$I_{CP}$	Collector Current (Pulse)	24	A
$I_B$	Base Current	6	A
$P_C$	Collector Dissipation ( $T_C=25^\circ\text{C}$ )	130	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$

### Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage	$I_C = 10\text{mA}, I_B = 0$	400			V
$I_{EBO}$	Emitter Cut-off Current	$V_{EB} = 7\text{V}, I_C = 0$			1	mA
$h_{FE}$	DC Current Gain	$V_{CE} = 5\text{V}, I_C = 5\text{A}$ $V_{CE} = 5\text{V}, I_C = 8\text{A}$	8 6		40 30	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 5\text{A}, I_B = 1\text{A}$ $I_C = 8\text{A}, I_B = 1.6\text{A}$ $I_C = 12\text{A}, I_B = 3\text{A}$			1 1.5 3	V V V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 5\text{A}, I_B = 1\text{A}$ $I_C = 8\text{A}, I_B = 1.6\text{A}$			1.2 1.6	V V
$C_{ob}$	Output Capacitance	$V_{CB} = 10\text{V}, f = 0.1\text{MHz}$		180		pF
$f_T$	Current Gain Bandwidth Product	$V_{CE} = 10\text{V}, I_C = 0.5\text{A}$	4			MHz
$t_{ON}$	Turn On Time	$V_{CC} = 125\text{V}, I_C = 8\text{A}$ $I_{B1} = - I_{B2} = 1.6\text{A}$ $R_L = 15,6\Omega$			1.1	$\mu\text{s}$
$t_{STG}$	Storage Time				3	$\mu\text{s}$
$t_F$	Fall Time				0.7	$\mu\text{s}$

\* Pulse test:  $PW \leq 300\mu\text{s}$ , Duty cycles  $\leq 2\%$  Pulse

# Typical Characteristics

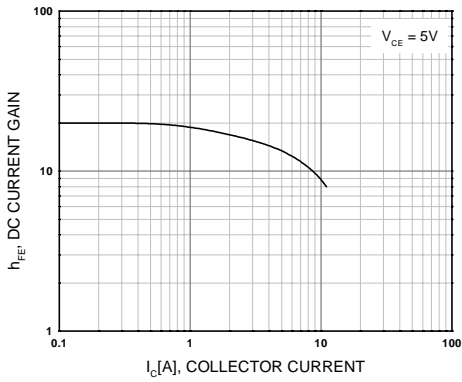


Figure 1. DC current Gain

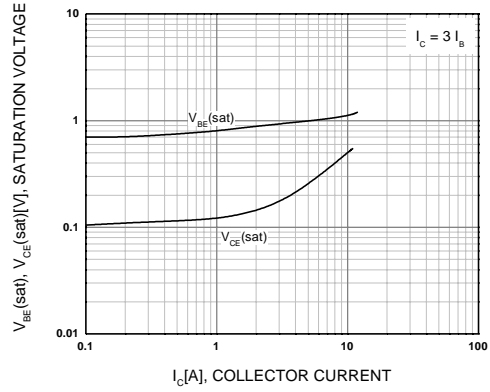


Figure 2. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

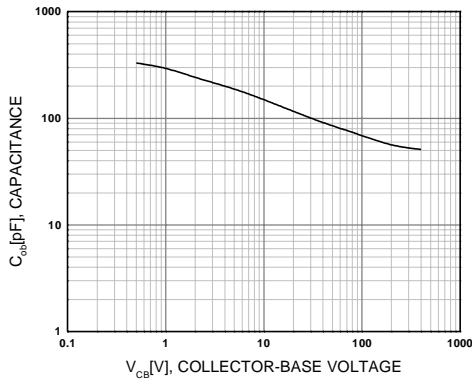


Figure 3. Collector Output Capacitance

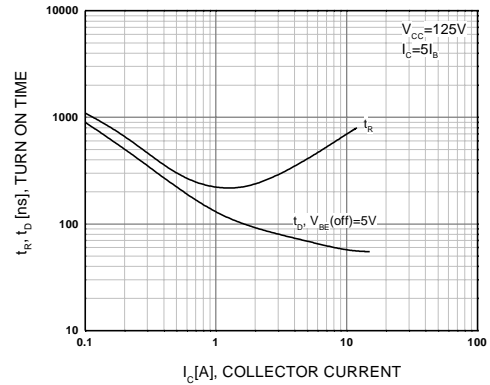


Figure 4. Turn On Time

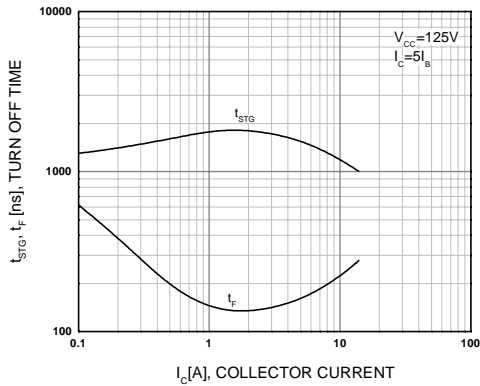


Figure 5. Turn Off Time

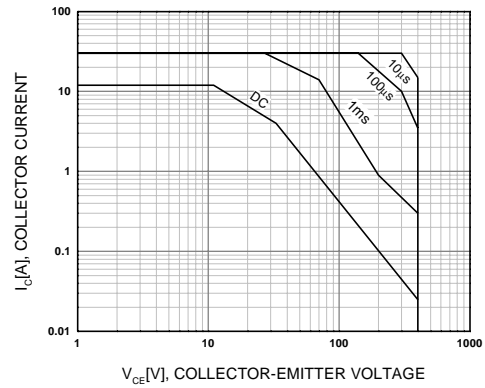


Figure 6. Forward Bias Safe Operating Area

# Typical Characteristics

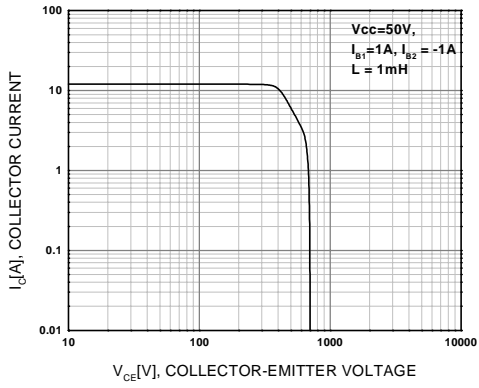


Figure 7. Reverse Bias Safe Operating Area

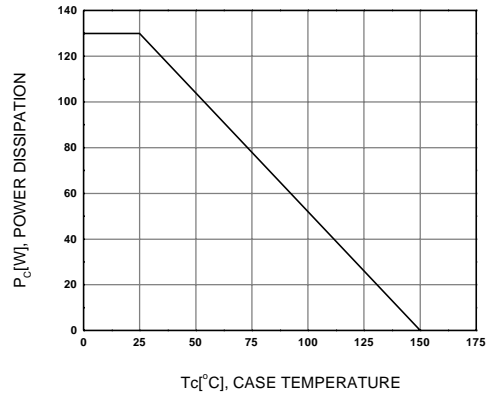
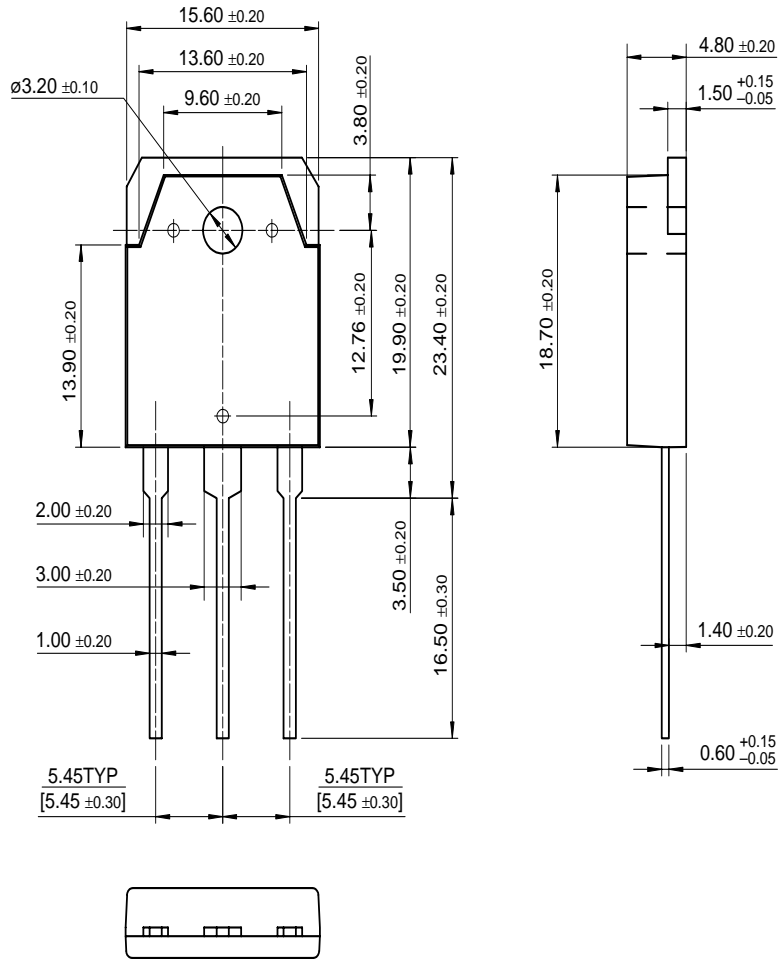


Figure 8. Power Derating

# Package Dimensions

FJA13009

## TO-3P



Dimensions in Millimeters

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